Upconversion cooling of Er-doped low-phonon fluorescent solids

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We report on a novel mechanism for laser cooling of fluorescent solids based on infrared-to-visible upconversion often found in rare-earth-doped low-phonon materials. This type of optical cooling presents some advantages with regards to onventional anti-Stokes ooling. Among them, it allows to obtain ooling in a broader range of frequen
ies around the bary
enter of the infrared emitting band.

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The demonstration by Epstein and coworkers [\[1](#page-2-1)] of laser-induced fluorescent cooling of an Yb-doped fluoride glass generated a surge of interest in this phenomenon be
ause it ould provide the means to fabri
ate the nextgeneration all-solid state ompa
t opti
al ryo
oolers for aerospacial applications $[2, 3, 4, 5]$ $[2, 3, 4, 5]$ $[2, 3, 4, 5]$ $[2, 3, 4, 5]$ $[2, 3, 4, 5]$ $[2, 3, 4, 5]$ and for the development of radiation-balanced lasers $[6, 7]$ $[6, 7]$ that are amenable of multiple applications in the fields of optical telecommunications and medicine. In this regard, it would be extremely useful being able to use optical cryocoolers made of active materials doped with different rare-earth ions that could be selected according to the targeted application. Unfortunately, in spite of more than two decades after the first experimental demonstration of this effect, only a small number of ions ould be used for this purpose. In parti
ular, anti-Stokes laser ooling has been demonstrated in a small number of crystal and glass host materials $[8]$ $[8]$ doped with Yb $[1]$, Tm $[9]$, and Er $[6]$ $[6]$, due to the inherent characteristics of the absorption and emission pro
esses in rare earth ions. Two are the main reasons that hinder the cooling efficiency: on the one hand, the presen
e of nonradiative transitions between the energy levels of the RE ion and, on the other hand, the presen
e of impurities in the host matrix that gives rise to parasiti absorptions that generate heat. Traditionally, host materials with very small phonons, so that the quantum efficiency of the electronic levels involved in the fluorescent transition is almost unity, with as few impurities as possible have been used in order to over
ome these two limitations. However, even in the optimal ase, the bulk cooling efficiency is still very small [\[6,](#page-2-6) 9]. In order to enhance the optical cooling efficiency -most crucial for developing practical applications- a number of ingenious innovations have been suggested, su
h as using a multipass configuration, increasing the active medium length by using optical fiber $[10]$, or taking advantage of additional ooling hannels, su
h as ooling in the superradiance regime [11], energy transfer fluorescent cooling [12], or using nanocrystalline powders doped with RE ions $[13]$ $[13]$.

In this paper, we present a novel pathway to effiient anti-Stokes laser ooling based on infrared-to-visible

up
onversion in RE-doped host materials that we will term from now on *upconversion cooling*. This mechanism makes use of the efficient ir-to-vis upconversion phenomena that is often found in RE-doped low-phonon host materials be
ause of the redu
ed multiphonon transition rates that makes possible for the pump level to act as an intermediate photon reservoir from whi
h additional up
onversion pro
esses take pla
e. This is the ase, for example, of Er-doped low-phonon potassium lead halide crystals KPb_2X_5 , $(X = \text{Cl}, \text{Br})$ -such as the one we reently employed to demonstrate anti-Stokes laser ooling in an Er-doped crystal-, where extremely efficient ir-to-vis upconversion has been demonstrated [\[14,](#page-2-14) 15].

The upconversion cooling process is summarized in figure [1](#page-1-0) by using the experimental energy levels of an Erdoped KPb_2Cl_5 crystal as a guiding example: upon cw pumping below the barycenter of the ${}^4I_{9/2}$ level, an electronic population reservoir is created in this level due to its long lifetime (2.4 ms). Part of this population de cays spontaneously to the ${}^4I_{15/2}$ level –emitting infrared photons- by means of a direct ${}^4I_{9/2}$ \rightarrow ${}^4I_{15/2}$ transition or through a sequential ${}^4I_{9/2} \rightarrow {}^4I_{13/2} \rightarrow {}^4I_{15/2}$ one. In any case, an anti-Stokes cycle occurs in which the energy of the fluorescent photons is slightly larger than the in
ident ones and, thus, a small amount of thermal vibrational energy (temperature) is removed from the system. Apart from this onventional laser ooling mechanism, in this system there can also exist additional emissions $\overline{-}$ in the visible range- due to the presence of upconversion processes [\[15](#page-3-0)]. These can be of two types: on the one hand, there is the possibility of sequential absorption by an electron in the excited state of another pumping photon that promotes it to a higher ex
ited level from where it later decays spontaneously, the so alled ex
ited state absorption (ESA) up
onversion. On the other hand, there can be an energy transfer upconversion (ETU) process in which two electrons initially in the excited state of two different ions interact with each other and, as a result, one of them decays to the ground state whereas the other one is promoted to a higher ex cited state, from where it later decays radiatively to the ground state. The population dynami
s of the ele
troni

Figure 1: (color online). Experimental Er^{3+} energy levels in a KPb₂Cl₅ host matrix. The straight arrows indicate the possible optical transitions that play a role in the electronic dynami
s. The wavy ones represent annihilation of phonons of energy $\hbar\Omega$. The labels used in the rate equations are also indicated.

levels taking part in all these processes can be cast in a very simple form by using a simple rate equation formalism

$$
N_{OAI} = N_0 + N_1 + N_2 + N_3 + N_4
$$
\n
$$
\frac{dN_1}{dt} = -W_{10} N_1 + \beta_{21} W_{21} N_2 + \gamma N_2^2 + \beta_{31} W_{31} N_3 + \beta_{41} W_{41} N_4 + \left(1 - \eta_e^{(1)}\right) W_1^{rad} N_1
$$
\n(2)

$$
\frac{dN_2}{dt} = \frac{P_{abs}^r}{h\nu_p} - \beta_{20}W_{20}N_2 - \beta_{21}W_{21}N_2 - 2\gamma N_2^2
$$

$$
-\sigma_{ESA}(\nu_p)\frac{I_p(t)}{h\nu_p}N_2 + \left(1 - \eta_e^{(2)}\right)W_2^{rad}N_2 \tag{3}
$$

$$
\frac{dN_3}{dt} = -\beta_{30}W_{30}N_3 - \beta_{31}W_{31}N_3 + \gamma N_2^2 + \left(1 - \eta_e^{(3)}\right)W_3^{rad}N_3\tag{4}
$$

$$
\frac{dN_4}{dt} = \sigma_{ESA}(\nu_p) \frac{I_p(t)}{h\nu_p} N_2 - \beta_{40} W_{40} N_4 - \beta_{41} W_{41} N_4 + \left(1 - \eta_e^{(4)}\right) W_4^{rad} N_4,
$$
\n(5)

where N_i $(i = 1 \dots 5)$ is the population of the *i*-th level (see figure [1](#page-1-0) for the nomenclature of the levels), N_{OAI} is the total population of optically active ions (OAI) in

the sample, $W_{ij} = W_i^{rad} + W_{i \to j}^{nr}$ is decay rate from level i to level j that includes both the radiative and the non-radiative (phonon assisted) decay rates, $\beta_{i0(1)}$ is the branch ratio for the $i \to 0(1)$ transition, γ is the strength of the ETU process in which one electron in level ${}^4I_{9/2}$ decays to the ${}^4I_{13/2}$ level and, at the same time, another electron in a different ion is promoted from the $^4I_{9/2}$ level to the ${}^4S_{3/2}$ one, $\eta_e^{(i)}$ is the fraction of photons emitted from the i -th level that actually leave the sample (not reabsorbed), ν_p is the frequency of the pumping laser, P_{abs}^r is the power absorbed resonantly by the sample at frequency ν_p , σ_{ESA} is the absorption cross-section at that same frequency, and $I_p(t)$ is the intensity of the laser beam. This set of equations annot be solved analyti ally in the general ase. However, it is quite easy to al
ulate the steady-state populations by using the ondition $\frac{dN_i}{dt} = 0$, $(i = 0...4)$. Once these populations are known, one can calculate the net power deposited in the sample by using the balan
e equation

$$
P_{net} = P_{abs}^r + P_{abs}^b - \eta_e^{(2)} W_2^{rad} h \bar{\nu}_2 N_2^{ss}
$$

$$
- \eta_e^{(3)} W_3^{rad} h \bar{\nu}_3 N_3^{ss} - \eta_e^{(4)} W_4^{rad} h \bar{\nu}_4 N_4^{ss}, \quad (6)
$$

where the frequencies $\bar{\nu}_i$ are the mean fluorescence frequency of the *i*-th emitting band and N_i^{ss} is the steadystate population of the i -th level. In this expression, the first three terms on the right hand side account for the standard anti-Stokes absorption ooling me
hanism, as described by Hoyt in Ref. [16.](#page-3-1) The fourth and fifth terms take into account the contribution from the ESA and the ETU processes to cooling, respectively. The sample temperature hange an be easily al
ulated from [6](#page-1-1) in the low pump-depletion limit (a reasonable approximation in single pass through the sample experiments) [16] and this quantity an be ast in the form

$$
\frac{\Delta T}{P_{in}} = \alpha_b + \alpha_r \left[1 - \tilde{\eta}_2 \frac{h\bar{\nu}_2}{h\nu_p} - \gamma \tilde{\eta}_3 \left(\frac{\tilde{\eta}_2 \tau_2^{rad}}{\eta_e^{(2)}} \right)^2 \right]
$$

$$
\times \alpha_r \frac{h\bar{\nu}_3}{h\nu_p} \frac{P_{in}}{h\nu_p} - \tilde{\eta}_4 \frac{\tilde{\eta}_2 \tau_2^{rad}}{\eta_e^{(2)}} \frac{\sigma_{ESA}(\nu_p)}{A} \frac{h\bar{\nu}_4}{h\nu_p} \frac{P_{in}}{h\nu_p} \right], \quad (7)
$$

where α_b is a background absorption coefficient nearly frequency independent [16], $\alpha_r(\nu_p)$ is the resonant part of the absorption coefficient, P_{in} is the input laser power, and these three quantities are related to the power absorbed by the sample (resonant or non-resonantly) through $P_{abs}^{r,nr} = P_{in} \frac{\alpha_{r,nr}}{\alpha_T}$ $\frac{a_{T,nr}}{\alpha_T}$ $[1 - \exp(-\alpha_T L)]$ with $\alpha_T =$ $\alpha_r + \alpha_{nr}$ and L the path length of the laser beam in the sample, $\tilde{\eta}_i = \frac{\eta_e^{(i)} W_i^{rad}}{\eta_e^{(i)} W_i^{rad} + \beta_{i0} W_{i \to 0}^{nr} + \beta_{i1} W_{i \to 1}^{nr}}$ is the generalized quantum efficiency of the *i*-th level when one of the fluorescence, $\tau_i^{rad} = \frac{1}{W_i^{rad}}$ is the intrinsic lifetime of the *i*-th level, and A is the cross-sectional area of the laser beam in the sample. By setting $\sigma_{ESA} = \gamma = 0$, one immediately re
overs the standard model for anti-Stokes laser cooling $[9]$, in which the onset of cooling (the frequency below which cooling occurs) is given by $\nu_0 = \frac{\alpha_r}{\alpha_T} \bar{\nu}_2$. However, the full model gives rise to a richer phenomenology. In order to simplify the subsequent dis cussion, let us assume that the generalized quantum efficiencies are almost unity and that is also the case for the fraction of photons escaping the sample $(\tilde{\eta}_i = \eta_e^{(i)} \approx 1)$. The first approximation is well justified in low-phonon materials su
h as the potassium lead halides mentioned in the introdu
tion for whi
h the multiphonon transition rates are almost negligible. This is further confirmed by photothermal deflection spectroscopy measurements in a number of RE-doped glasses and crystals. The second approximation is more arguable, be
ause it depends of a number of fa
tors su
h as the geometry of sample, its index of refraction, etc. However, with regards to analyzing expression [7,](#page-1-2) we an always make the substitution $\frac{\tau_i^{rad}}{\eta_e^{(i)}} \to \tilde{\tau}_i^{rad}$, where the later lifetime is a renormalized one (that is, a photon es
aping fra
tion smaller than one an be interpreted as a longer intrinsi lifetime of the emitting level), whi
h does not alter any of the following results whatsoever.

Let us start by considering a case in which standard anti-Stokes ooling is negligible when ompared with the upconversion channels, i.e., $\tau_2^{rad} \to \infty$. In this case, there is an input power threshold for cooling, that is, we need to provide a minimum input power to the sample in order to make $\Delta T < 0$. This power threshold is easily calculated to be

$$
P_{in}^{(0)} = \frac{\alpha_T}{\alpha_r} \frac{(h\nu_p)^2}{\tau_2^{rad}} (h\nu_{up})^{-1}, \qquad (8)
$$

where

$$
h \nu_{up} = \gamma \tau_2^{rad} \alpha_r L \, h \bar{\nu}_3 + \frac{\sigma_{ESA}(\nu_p)}{A} h \bar{\nu}_4. \tag{9}
$$

Interestingly, this expression shows that up
onversion cooling occurs by means of any of the upconversion channels. This is quite useful is systems where the operating up
onversion me
hanism an be sele
ted by adequately tuning the pumping frequency, such as it is the case in potassium lead halide matrices [\[14](#page-2-14), [15](#page-3-0)]. If we now go back to the general model, another important conclusion com-ing out from equation [7](#page-1-2) is that the onset of cooling, that is, the pumping frequency below which cooling occurs is larger when upconversion is present. The exact cutoff frequency depends on both $\alpha_r(\nu_p)$ and $\sigma_{ESA}(\nu_p)$ and, as such, cannot be put in a closed form in the general case. However, near the resonan
e, where these two fun
tions can be approximated by their values at the maximum α_0 and σ_0 and the constant background absorption can be neglected, the cutoff frequency can be put in the form

$$
\nu_0^{up} \approx \nu_0 + \frac{\nu_{up} \tau_2^{rad} P_{in}}{h \nu_0}.\tag{10}
$$

It is important to notice that $\nu_0^{up} > \nu_0$. This, in fact, is quite reasonable, as one has additional hannels for extracting energy from the system when upconversion is present, so that cooling can be more efficient. What it is really interesting is the fact that if the pumping beam is very intense or the upconversion process very efficient $(\nu_{up} \gg 1)$, the onset of cooling could be located above the bary
enter of the pumping level, that is, in its Stokes part.

In conclusion, we have presented a novel mechanism for laser ooling based on infrared-to-visible up
onversion pro
esses. It has been analyzed by using a simple rate equation formalism from which it is concluded that uponversion ooling presents a number of advantages with regards to standard anti-Stokes ooling. Among these there is the possibility to control the onset of cooling by using the pumping power or to select the active upconversion me
hanism by adequately tuning the pumping frequency, which can be very useful for frequency selective appli
ations. We hope that the results presented in this work will en
ourage other resear
hers to further investigate the role that upconversion cooling could play in the development of highly efficient solid state refrigeration appli
ations.

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